AMT-A0030 2 GHz to 18 GHz 8W 41 dB Gain Broadband High Power Amplifier Module

Data Sheet

Features

- 2 GHz to 18 GHz Frequency Range
- Typical Psat power > +39 dBm
- Gain 43 dB
- High Efficiency
- Internally Regulated
- Operates from a Single +28V Supply
- Unconditionally Stable
- Compact Size
- State-of-the-Art GaN Technology

Description

The AMT-A0030 is a Broadband 8 W power amplifier in a compact size. The performance is achieved through the use of AMTI's proprietary matching technology and latest in GaN technology. The amplifier I/Os are Internally matched to 50 Ohms and are DC blocked. The AMT-A0030 is ideal for use as extending power range of test equipment, EW systems or where broadband amplification and power are required in a Hi-Rel communications system for Commercial or Military applications

MAXIMUM RATINGS¹

Parameter	Symbol	Units	MIN	MAX
Operating Temperature – Case	Т _{мо}	° C	0	+65
Storage Temperature - Case	T _{MS}	° C	-20	+125
RF Input power (CW)	Pin	dBm		+20
Die T _{Junction}	TJ	° C		+150
DC Current		А		1.6
Positive Supply Voltage	V _{+SS}	V	+15	+29

Appropriate Heat sink must be used

Do not turn on RF without loading RFout

1.Stresses above those listed under "Absolute Maximum Rating" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





Applications

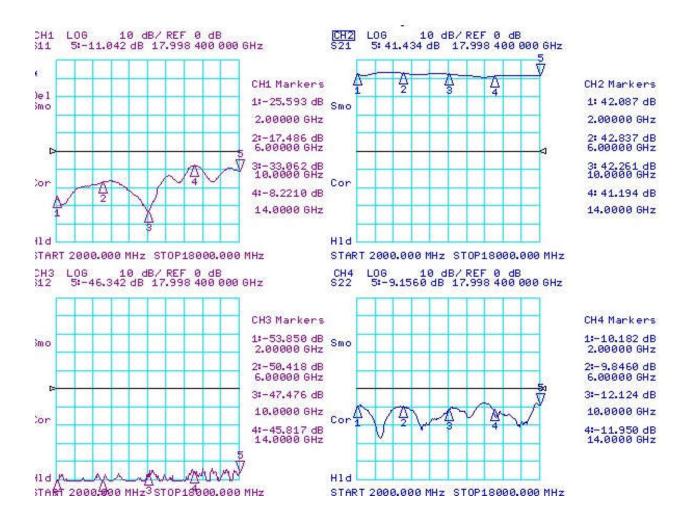
- Test Equipment
- EW Systems
- Lab Applications
- Radar

ELECTRICAL SPECIFICATIONS @ 23°C

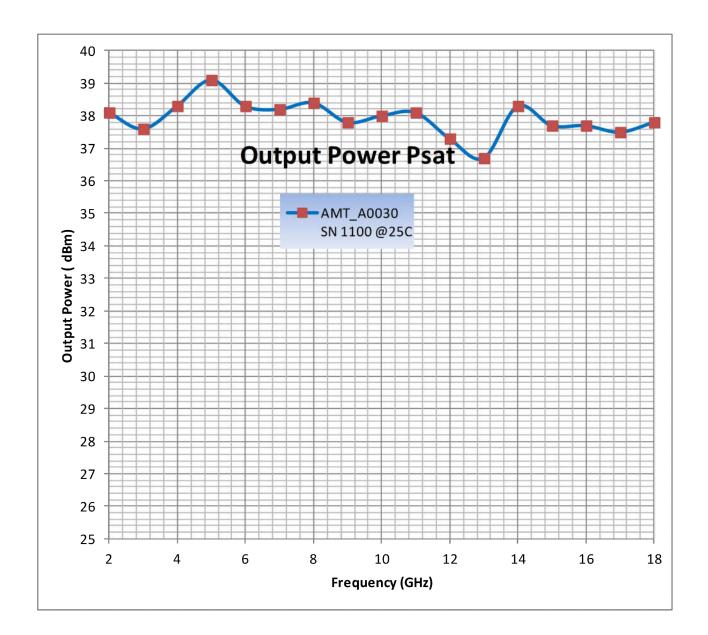
Parameter	Conditions	Units	MIN	Typical	MAX
Frequency Range		GHz	2		18
Gain	Small Signal	dB	38	43	
Gain Flatness		dB		±1.5	±2
Output Power (Psat)	Saturated Output power	dBm	36	38.5	
OIP3	OPI3 measured @ 5GHz Two tone F1-F2= 10MHz	dB		45	
Noise Figure		dB			8
RF Input Impedance	Reference to 50 ohms VSWR	dB		1.6:1	2.3:1
RF Output Impedance	Reference to 50 ohms VSWR	dB		1.8:1	2.3:1
Supply Voltage Positive:		v		+28	
Supply Current	Small signal	mA		550	
Positive:	Psat	A		1.4	

Notes: 1/ Unconditional Stability

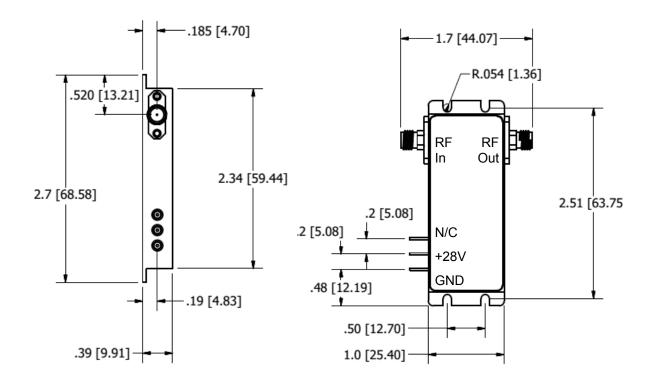
Customized configurations of the above specifications are available







Package Outline: Units are in Inches [mm] SMA Connectorized Inch-



Field replaceable SMA Connectors Housing Material Aluminum, Nickel Plated

Note: The unit must be attached to proper heat sink with thermal interface material (Thermal Pad or Thermal Grease)

Model Number	Description	Hermeticity	Package	
AMT-A0030	SMA Female	Non-Hermetic	Outline: M119	

Contact us for custom configurations and special requirements.

Our highly experienced team of engineers can quickly identify and implement innovative solutions using latest technology to improve performance and reduce cost.

- Add additional functionality: Input limiter, Temperature compensation, Amplitude/Phase matching, Amplitude/Phase Tracking, Automatic Gain control, Gain sloping, Bypass path, Specific supply voltage, Regulation, Power detector, Health status, and others
- Integrated: Filters, Switches, Limiter, Digital attenuator, Phase shifter, Microcontroller, Multiple amplifiers, Switch matrix, Comb generators and others
- Mechanical: Custom packages Surface Mount, Connectorized, Waveguide, Carrier, Drop-in, Hermetic and others

Agile Microwave Technology Inc is the logical choice for all your commercial or military RF/Microwave components/module requirements.

Note: Available options are model dependent, contact us for details

